

CMOS Expandable 4-Wide 2-Input AND-OR-INVERT Gate

High-Voltage Types (20-Volt Rating)

CD4086B contains one 4-wide 2-input AND-OR-INVERT gate with an INHIBIT/EXP input and an ENABLE/ EXP input. For a 4-wide A-O-I function INHIBIT/ $\overline{\text{EXP}}$ is tied to V_{SS} and ENABLE/EXP to VDD. See Fig.10 and its associated explanation for applications where a capability greater than 4-wide is required.

The CD4086B types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

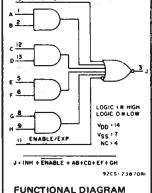
MAXIMUM RATINGS, Absolute-Maximum Values:

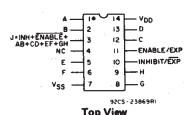
Features:

- Medium-speed operation tpHL = 90 ns; tpLH = 140 ns (typ.) at 10 V
- **INHIBIT and ENABLE inputs**
- **Buffered** outputs
- 100% tested for quiescent current at 20 V
 - Maximum input leakage current of 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package termperature range):

- 2.5 V at VDD v Standardized, symmetrical output
- characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"







3

COMMERCIAL CMOS HIGH VOLTAGE ICs

TERMINAL ASSIGNMENT

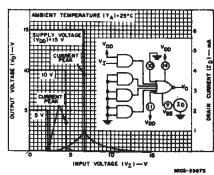


Fig. 1 - Typical voltage and current transfer characteristics.

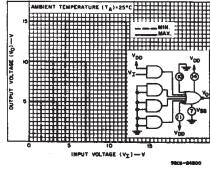


Fig. 2 - Minimum and maximum voltage transfer characteristics.

DC SUPPLY-VOLTAGE RANGE, (VDD) Voltages referenced to V_{SS} Terminal)-0.5V to +20V POWER DISSIPATION PER PACKAGE (PD): For T_A = +100°C to +125°C.....Derate Linearity at 12mW/°C to 200mW DEVICE DISSIPATION PER OUTPUT TRANSISTOR OPERATING-TEMPERATURE RANGE (TA)......-55°C to +125°C STORAGE TEMPERATURE RANGE (Tsto).....-65°C to +150°C LEAD TEMPERATURE (DURING SOLDERING):

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

	LIN	LIMITS			
CHARACTERISTIC	MIN.	MAX.	UNITS		
Supply-Voltage Range (For T _A = Full Package- Temperature Range)	3	18	v		

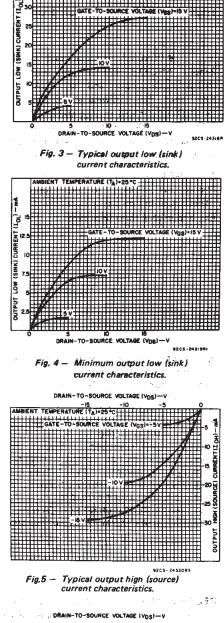
CD4086B Types

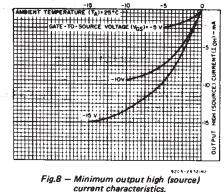
ы)._е

1

STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERISTIC	CONDITIONS VO VIN VDD (V) (V) (V)			VO VIN VDD				MPERATURES (°C) +25 Min. Typ. Max.			UNITS
Quiescent	_	0,5	5	1	1	30	30		0.02	1	· · · · ·
Device		0,10	10	2	2	60	60	<u> </u>	0.02	2	
Current		0,15	15	4	4	120	120		0.02	4	μA
IDD Max.	-	0,20	20	20	20	600	600	_	0.04	20	
Output Low		· · · · · ·				-				(1)	
(Sink)	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	26/3 1		
Current,	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51		-	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Volt-											
age:	_	0,5	5		0.0)5		_	0	0.05	
Low-Level,		0,10	10		0.0)5			0	0.05	
V _{OL} Max.	. 7	0,15	15		0.0) 5	· ·		Q	0.05	v
Output Volt-		A.4.									v
age:		0,5	5		4.9	95		4.95	5	_	
High-Level,	-	0,10	10		9.9	95		9.95	10	_	1
V _{OH} Min.	. –	0,15	15		14.	95		14.95	15	-	
Input Low	0.5,4.5	-	5		1.	5		_	_	1.5	
Voltage,	1,9	-	10		3			_	-	3	
VIL Max.	1.5,13.5	-	15		4				_	4	
Input High	0.5,4.5	_	5	3.5 3.5				_	_	V	
Voltage,	1,9	<u> </u>	10					7	_	_	
VIH Min.	1.5,13.5		15		1	1 .		11	-		
Input Current, I _{IN} Max.		0,18	18	±0.1	±0.1	±1	_±1		±10-5	±0.1	μΑ





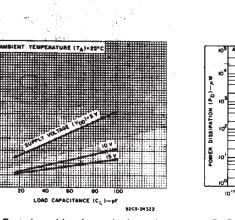
8

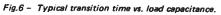
ē

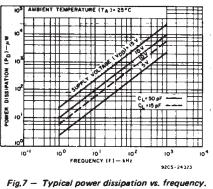
THL

TIME (1)

ğ







12.1

Ċ,

CD4086B Types

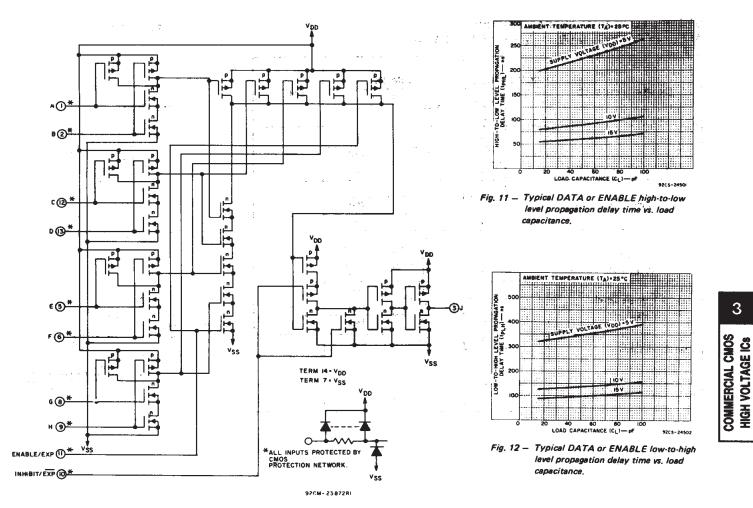


Fig. 9 - CD4086B schematic diagram.

VSS A2

82

cz

D2 E2

F2

G 2

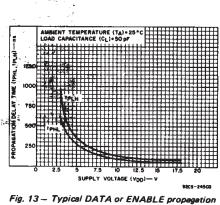
н2

9205-23871

ENABLE / EXP;

J2-AIBI+CI DI+EI FI+GI HI + A2 82+C2 D2+E2 F2+G2 H2

Fig. 10 - Two CD4086B's connected as an 8-wide 2-input A-O-I gate.



3

delay time vs. supply voltage.

Fig. 10 above shows two CD4086's utilized to obtain an 8-wide 2-input A-O-I function. The output (J1) of one CD4086 is fed directly to the ENABLE/EXP2 line of the second CD4086. In a similar fashion, any

INHIBIT/EXP

AI

81

cı D1

ΕI FI

GI

ы

ENAULE/EXP

vod

NAND gate output can be fed directly into the ENABLE/EXP input to obtain a 5-wide A-O-I function. In addition, any AND gate output can be fed directly into the IN-HIBIT/EXP input with the same result.

DYNAMIC ELECTRICAL CHARACTERISTICS

50

At $T_A = 25^{\circ}C$; Input t_r , $t_f = 20$ ns, $C_L = 50$ pF, $R_L = 200$ k Ω

	CONDI	TIONS	LI		
CHARACTERISTIC		V _{DD} (V)	ТҮР.	MAX.	UNITS
Propagation Delay Time		5	225	450	
(Data):		10	90	180	ns
High-to-Low Level, tpHL		15	60	120	
Low-to-High Level, t _{PLH}		5	310	620	
		10	125	250	ns
		15	90	180	1
Propagation Delay Time		5	150	300	
(Inhibit): High-to-Low		10	60	120	s ns
Level, tPHL(INH)		15	40	80	1
Level en Historia en el		5	250	500	
Low-to-High Level,		10	100	200	ns
^t PLH(INH)		15	70	140	1
Transision Time		5	100	200	
Transition Time,		10	50	100	ns
^t THL ^{, t} TLH		15	40	80]
Input Capacitance CIN	Any	Input	5	7.5	pF

TEST CIRCUITS

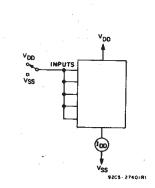


Fig. 14 - Quiescent device current,

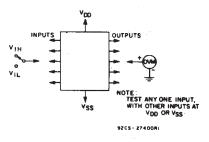
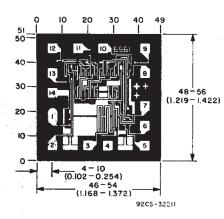


Fig. 15 - Input voltage.



4.0

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .

Dimensions and Pad Layout for the CD4086BH

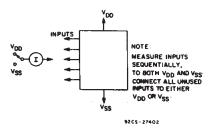


Fig. 16 - Input leakage current.

in in inge



www.ti.com

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
CD4086BE	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD4086BEE4	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD4086BF3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	
CD4086BM	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD4086BME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD4086BMG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD4086BMT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD4086BMTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD4086BMTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



www.ti.com

20-Aug-2011

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4086B, CD4086B-MIL :

• Catalog: CD4086B

• Military: CD4086B-MIL

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

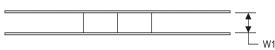
www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS

Texas Instruments





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4086BMT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4086BMT	SOIC	D	14	250	367.0	367.0	38.0

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46C and to discontinue any product or service per JESD48B. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Mobile Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconnectivity		

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2012, Texas Instruments Incorporated